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1500 Main Street, Suite 912  
Springfield, MA 01115  
Telephone: (413) 731-3100ATTORNEY DOCKET NO.  
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APPLICANT: Burgmair et al.

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EXAMINER: Diana C. Garrity

**INFORMATION DISCLOSURE  
STATEMENT BY APPLICANT****U.S. PATENT DOCUMENTS**

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
/D.G./	A						
/D.G./	B						
/D.G./	C						
/D.G./	D						
/D.G./	E						
/D.G./	F						
/D.G./	G						

**FOREIGN PATENT DOCUMENTS**

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION YES NO
/D.G./	H	JP 08189870	7/23/1996	Japan	9	12	Yes-Abstract
/D.G./	I	JP 56100350	8/12/1981	Japan	27	30	Yes-Abstract
/D.G./	J	JP 63171355	7/15/1988	Japan	27	30	Yes-Abstract
/D.G./	K						

**OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)**

EXAMINER INITIAL		
/D.G./	L	Matsushima Toshinori et al., "Organic-inorganic field effect transistor with SnI-based perovskite channel layer using vapour phase deposition technique," Proceedings of the SPIE-The International Society for Optical Engineering, 2003, Vol. 5217. Pages 43-54 ( <b>ABSTRACT</b> ) CAPLUS [online]
/D.G./	M	Sudholter, Ernst et al., "Modification of ISFETs by covalent anchoring of poly(hydroxyethylmethacrylate)hydrogel. Introduction of thermodynamically defined semiconductor-sensing membrane interface." Analytica Chimica Acta, 1990, Vol. 230, No. 1, Pages 59-65 ( <b>ABSTRACT</b> ) CAPLUS [online]
/D.G./	N	
/D.G./	O	
/D.G./	P	
/D.G./	Q	

EXAMINER

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DATE CONSIDERED

03/20/2009

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**Initial if citation considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.**

ALL REFERENCES CONSIDERED EXCEPT WHERE LINED THROUGH. /D.G./